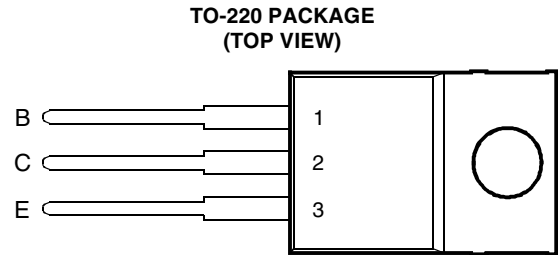


- 30 W at 25°C Case Temperature
- 2 A Continuous Collector Current
- 4 A Peak Collector Current
- Customer-Specified Selections Available



Pin 2 is in electrical contact with the mounting base.

MDTRACA

absolute maximum ratings at 25°C case temperature (unless otherwise noted)

RATING		SYMBOL	VALUE	UNIT
Collector-emitter voltage ($R_{BE} = 100 \Omega$)	BD239D	V_{CER}	160	V
	BD239E		180	
	BD239F		200	
Collector-emitter voltage ($I_B = 0$)	BD239D	V_{CEO}	120	V
	BD239E		140	
	BD239F		160	
Emitter-base voltage		V_{EBO}	5	V
Continuous collector current		I_C	2	A
Peak collector current (see Note 1)		I_{CM}	4	A
Continuous base current		I_B	0.6	A
Continuous device dissipation at (or below) 25°C case temperature (see Note 2)		P_{tot}	30	W
Continuous device dissipation at (or below) 25°C free air temperature (see Note 3)		P_{tot}	2	W
Unclamped inductive load energy (see Note 4)		$\frac{1}{2}LI_{C2}$	32	mJ
Operating junction temperature range		T_j	-65 to +150	°C
Storage temperature range		T_{stg}	-65 to +150	°C
Lead temperature 3.2 mm from case for 10 seconds		T_L	250	°C

- NOTES: 1. This value applies for $t_p \leq 0.3$ ms, duty cycle $\leq 10\%$.
 2. Derate linearly to 150°C case temperature at the rate of 0.24 W/°C.
 3. Derate linearly to 150°C free air temperature at the rate of 16 mW/°C.
 4. This rating is based on the capability of the transistor to operate safely in a circuit of: $L = 20$ mH, $I_{B(on)} = 0.4$ A, $R_{BE} = 100 \Omega$, $V_{BE(off)} = 0$, $R_S = 0.1 \Omega$, $V_{CC} = 20$ V.

PRODUCT INFORMATION

electrical characteristics at 25°C case temperature

PARAMETER		TEST CONDITIONS			MIN	TYP	MAX	UNIT
$V_{(BR)CEO}$	Collector-emitter breakdown voltage	$I_C = 30 \text{ mA}$ $I_B = 0$ (see Note 5)	BD239D	120			V	
			BD239E	140				
			BD239F	160				
I_{CES}	Collector-emitter cut-off current	$V_{CE} = 160 \text{ V}$ $V_{CE} = 180 \text{ V}$ $V_{CE} = 200 \text{ V}$	$V_{BE} = 0$	BD239D			0.2	mA
			$V_{BE} = 0$	BD239E			0.2	
			$V_{BE} = 0$	BD239F			0.2	
I_{CEO}	Collector cut-off current	$V_{CE} = 90 \text{ V}$	$I_B = 0$				0.3	mA
I_{EBO}	Emitter cut-off current	$V_{EB} = 5 \text{ V}$	$I_C = 0$				1	μA
h_{FE}	Forward current transfer ratio	$V_{CE} = 4 \text{ V}$ $V_{CE} = 4 \text{ V}$	$I_C = 0.2 \text{ A}$	(see Notes 5 and 6)	40			
			$I_C = 1 \text{ A}$		15			
$V_{CE(sat)}$	Collector-emitter saturation voltage	$I_B = 0.2 \text{ A}$	$I_C = 1 \text{ A}$	(see Notes 5 and 6)			0.7	V
V_{BE}	Base-emitter voltage				$V_{CE} = 4 \text{ V}$	$I_C = 1 \text{ A}$	(see Notes 5 and 6)	
h_{fe}	Small signal forward current transfer ratio	$V_{CE} = 10 \text{ V}$	$I_C = 0.2 \text{ A}$	$f = 1 \text{ kHz}$	20			
$ h_{fe} $	Small signal forward current transfer ratio	$V_{CE} = 10 \text{ V}$	$I_C = 0.2 \text{ A}$	$f = 1 \text{ MHz}$	3			

NOTES: 5. These parameters must be measured using pulse techniques, $t_p = 300 \mu\text{s}$, duty cycle $\leq 2\%$.

6. These parameters must be measured using voltage-sensing contacts, separate from the current carrying contacts.

thermal characteristics

PARAMETER		MIN	TYP	MAX	UNIT
$R_{\theta JC}$	Junction to case thermal resistance			4.17	$^{\circ}\text{C/W}$
$R_{\theta JA}$	Junction to free air thermal resistance			62.5	$^{\circ}\text{C/W}$

resistive-load-switching characteristics at 25°C case temperature

PARAMETER		TEST CONDITIONS †			MIN	TYP	MAX	UNIT
t_{on}	Turn-on time	$I_C = 200 \text{ mA}$	$I_{B(on)} = 20 \text{ mA}$	$I_{B(off)} = -20 \text{ mA}$		0.3		μs
t_{off}	Turn-off time				$V_{BE(off)} = -3.4 \text{ V}$	$R_L = 150 \Omega$	$t_p = 20 \mu\text{s}$, dc $\leq 2\%$	

† Voltage and current values shown are nominal; exact values vary slightly with transistor parameters.

TYPICAL CHARACTERISTICS

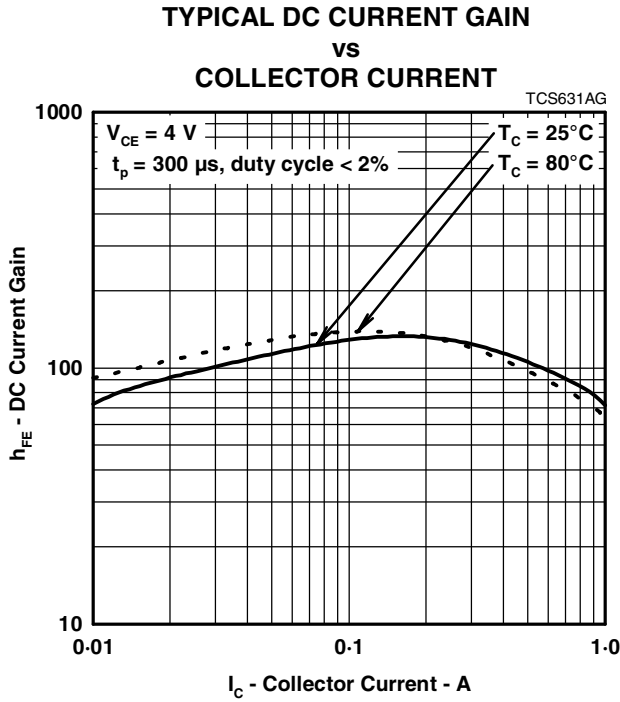


Figure 1.

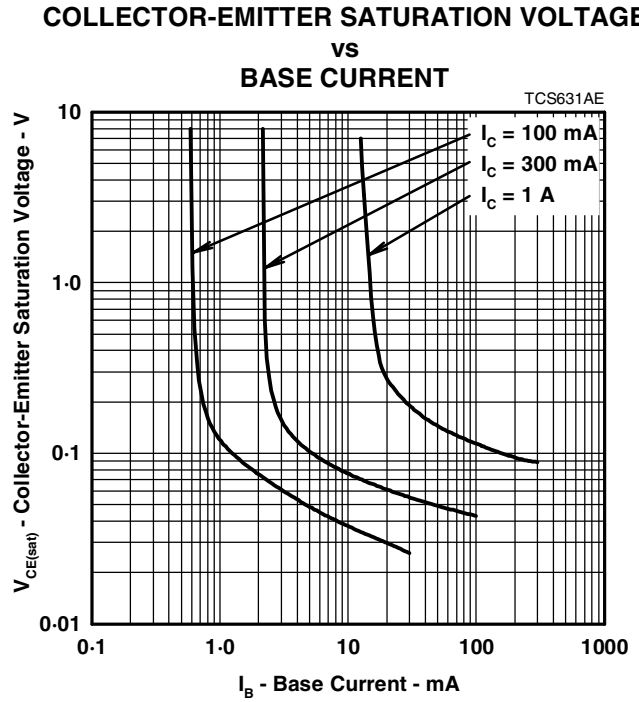


Figure 2.

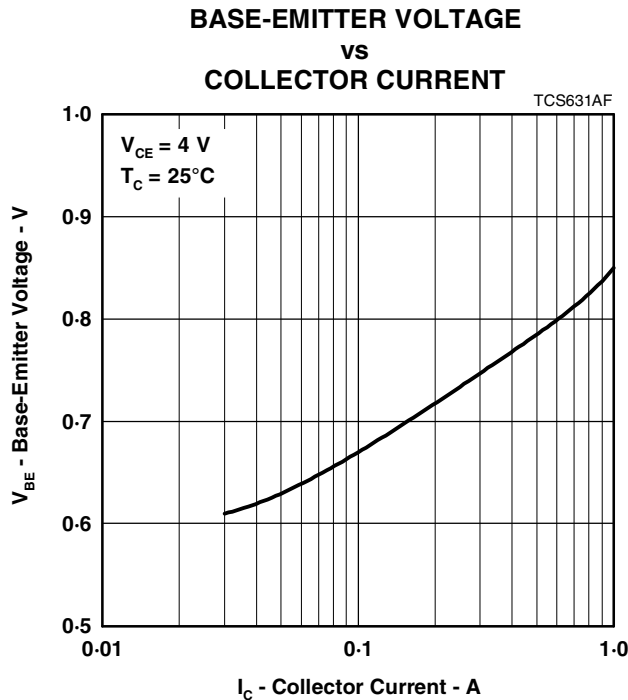


Figure 3.

PRODUCT INFORMATION

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MAXIMUM SAFE OPERATING REGIONS

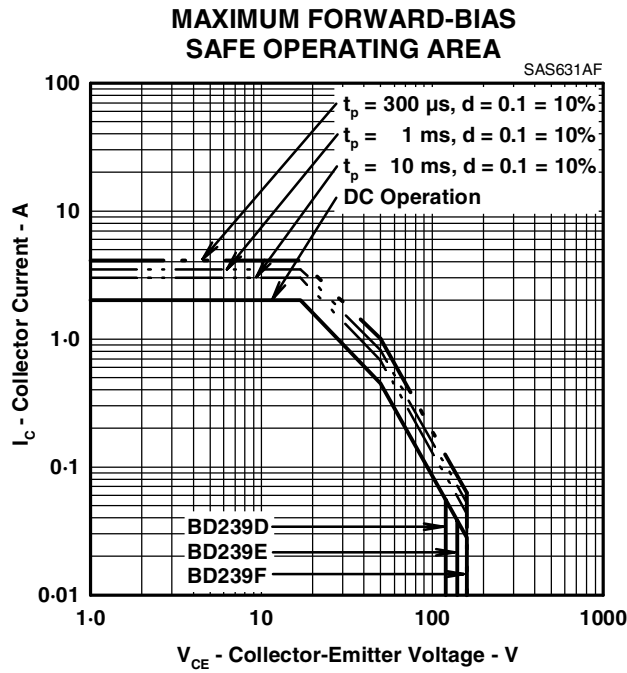


Figure 4.

THERMAL INFORMATION

**MAXIMUM POWER DISSIPATION
vs
CASE TEMPERATURE**

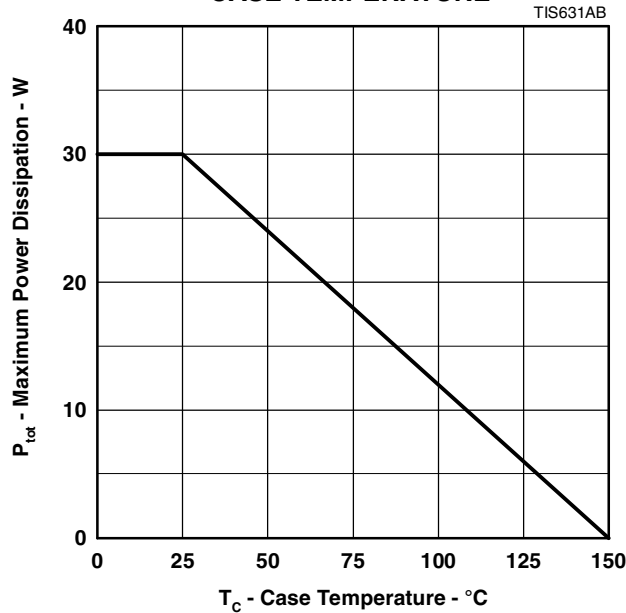


Figure 5.

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